



BTA/BTB24, BTA25, BTA26 and T25 Series

SNUBBERLESS™ & STANDARD

25A TRIACs

MAIN FEATURES:

Symbol	Value	Unit
$I_{T(RMS)}$	25	A
V_{DRM}/V_{RRM}	600 and 800	V
$I_{GT} (Q_1)$	35 to 50	mA

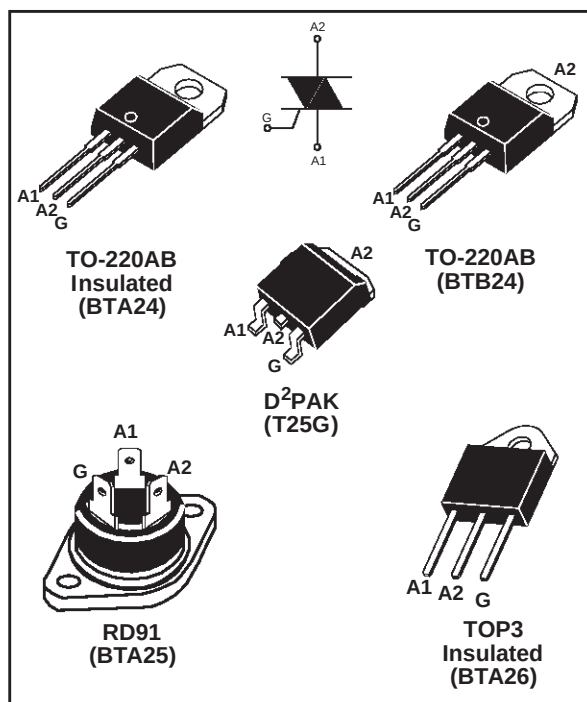
DESCRIPTION

Available either in through-hole or surface and T25 mount packages, the BTA/BTB24-25-26 triac series is suitable for general purpose AC power switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, water heaters, induction motor starting circuits...or for phase control operation in high power motor speed controllers, soft start circuits...The snubberless versions (BTA/BTB...W and T25 series) are specially recommended for use on inductive loads, thanks to their high commutation performances.

By using an internal ceramic pad, the BTA series provides voltage insulated tab (rated at 2500V RMS) complying with UL standards (File ref.: E81734).

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	D PAK TO-220AB	$T_c = 100^\circ\text{C}$	25	A
		RD91 TOP3 Ins.	$T_c = 90^\circ\text{C}$		
		TO-220AB Ins.	$T_c = 75^\circ\text{C}$		
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25°C)	F = 60 Hz	t = 16.7 ms	260	A
		F = 50 Hz	t = 20 ms	250	
I_t	I_t Value for fusing	tp = 10 ms		340	A s
di/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, tr ≤ 100 ns	F = 120 Hz	$T_j = 125^\circ\text{C}$	50	A/μs
V_{DSM}/V_{RSM}	Non repetitive surge peak off-state voltage	tp = 10 ms	$T_j = 25^\circ\text{C}$	V_{DRM}/V_{RRM} + 100	V
I_{GM}	Peak gate current	tp = 20 μs	$T_j = 125^\circ\text{C}$	4	A
$P_{G(AV)}$	Average gate power dissipation	$T_j = 125^\circ\text{C}$		1	W
T_{stg} T_j	Storage junction temperature range Operating junction temperature range	- 40 to + 150 - 40 to + 125			$^\circ\text{C}$



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ELECTRICAL CHARACTERISTICS (T_j = 25°C, unless otherwise specified)

■ SNUBBERLESS™ (3 Quadrants) T25-G, BTA/BTB24...W, BTA25...W, BTA26...W

Symbol	Test Conditions	Quadrant		T25	BTA/BTB		Unit
				T2535	CW	BW	
I _{GT} (1)	V _D = 12 V R _L = 33 Ω	I - II - III	MAX.	35	35	50	mA
V _{GT}		I - II - III	MAX.	1.3			V
V _{GD}	V _D = V _{DRM} R _L = 3.3 kΩ T _j = 125°C	I - II - III	MIN.	0.2			V
I _H (2)	I _T = 500 mA		MAX.	50	50	75	mA
I _L	I _G = 1.2 I _{GT}	I - III	MAX.	70	70	80	mA
		II		80	80	100	
dV/dt (2)	V _D = 67 % V _{DRM} gate open T _j = 125°C		MIN.	500	500	1000	V/μs
(dI/dt) _c (2)	Without snubber T _j = 125°C		MIN.	13	13	22	A/ms

■ STANDARD (4 Quadrants): BTA25...B, BTA26...B

Symbol	Test Conditions	Quadrant		Value	Unit
I _{GT} (1)	V _D = 12 V R _L = 33 Ω	I - II - III IV	MAX.	50 100	mA
V _{GT}		ALL	MAX.	1.3	V
V _{GD}	V _D = V _{DRM} R _L = 3.3 kΩ T _j = 125°C	ALL	MIN.	0.2	V
I _H (2)	I _T = 500 mA		MAX.	80	mA
I _L	I _G = 1.2 I _{GT}	I - III - IV	MAX.	70	mA
		II		160	
dV/dt (2)	V _D = 67 % V _{DRM} gate open T _j = 125°C		MIN.	500	V/μs
(dV/dt) _c (2)	(dI/dt) _c = 13.3 A/ms T _j = 125°C		MIN.	10	V/μs

STATIC CHARACTERISTICS

Symbol	Test Conditions			Value	Unit
V _{TM} (2)	I _{TM} = 35 A tp = 380 μs	T _j = 25°C	MAX.	1.55	V
V _{to} (2)	Threshold voltage	T _j = 125°C	MAX.	0.85	V
R _d (2)	Dynamic resistance	T _j = 125°C	MAX.	16	mΩ
I _{DRM}	V _{DRM} = V _{RRM}	T _j = 25°C	MAX.	5	μA
I _{RRM}		T _j = 125°C		3	mA

Note 1: minimum I_{GT} is guaranteed at 5% of I_{GT} max.

Note 2: for both polarities of A2 referenced to A1

THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case (AC)		D PAK TO-220AB	°C/W
			RD91 (Insulated) TOP3 Insulated	
			TO-220AB Insulated	
$R_{th(j-a)}$	Junction to ambient	S = 1 cm	D PAK	°C/W
			TOP3 Insulated	
			TO-220AB	
			TO-220AB Insulated	

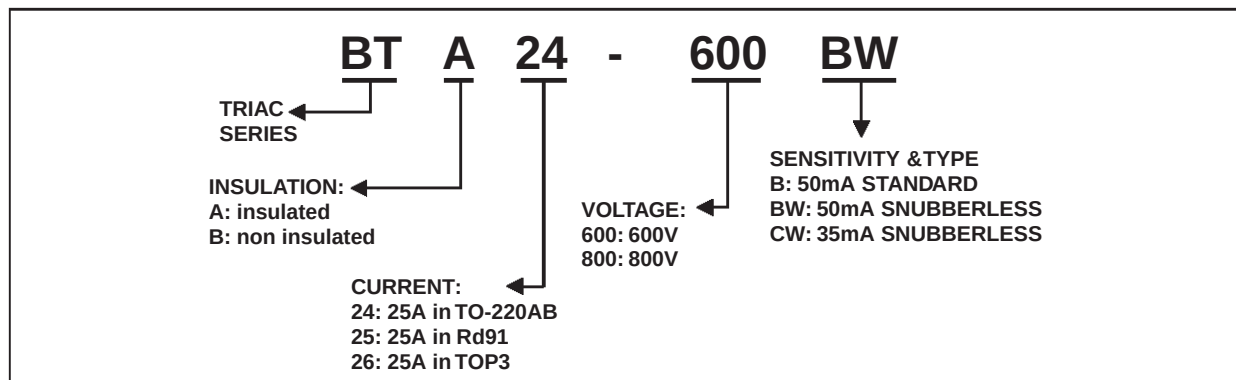
S: Copper surface under tab

PRODUCT SELECTOR

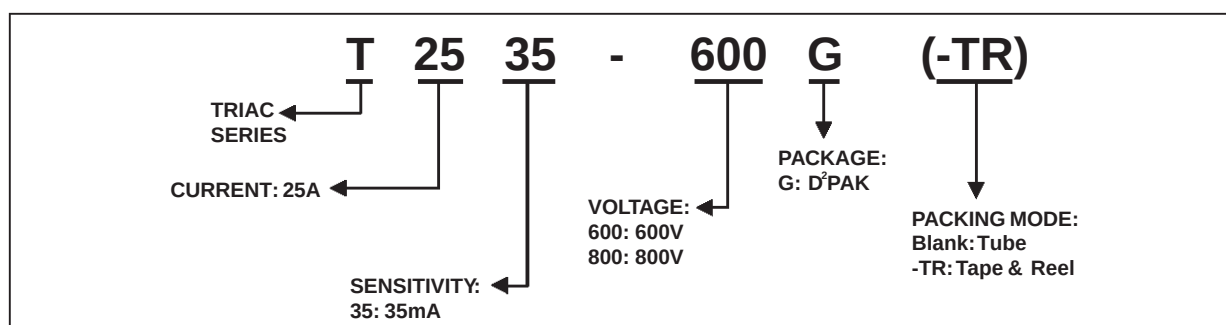
Part Number	Voltage (xxx)		Sensitivity	Type	Package
	600 V	800 V			
BTA/BTB24-xxxBW	X	X	50 mA	Snubberless	TO-220AB
BTA/BTB24-xxxCW	X	X	35 mA	Snubberless	TO-220AB
BTA25-xxxB	X	X	50 mA	Standard	RD-91
BTA25-xxxBW	X	X	50 mA	Snubberless	RD-91
BTA25-xxxCW	X	X	35 mA	Snubberless	RD-91
BTA26-xxxB	X	X	50 mA	Standard	TOP3 Ins.
BTA26-xxxBW	X	X	50 mA	Snubberless	TOP3 Ins.
BTA26-xxxCW	X	X	35 mA	Snubberless	TOP3 Ins.
T2535-xxxG	X	X	35 mA	Snubberless	D PAK

BTB: Non insulated TO-220AB package

ORDERING INFORMATION



BTA/BTB24, BTA25, BTA26 and T25 Series



OTHER INFORMATION

Part Number	Marking	Weight	Base quantity	Packing mode
BTA/BTB24-xxxyz	BTA/BTB24xxxyz	2.3 g	250	Bulk
BTA25-xxxyz	BTA25xxxyz	20 g	25	Bulk
BTA26-xxxyz	BTA26xxxyz	4.5 g	120	Bulk
T2535-xxxG	T2535xxxG	1.5 g	50	Tube
T2535-xxxG-TR	T2535xxxG	1.5 g	1000	Tape & reel

Note: xxx= voltage, y = sensitivity, z = type

Fig. 1: Maximum power dissipation versus RMS on-state current (full cycle).

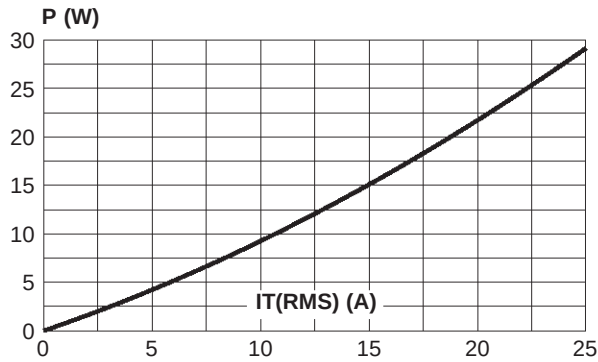


Fig. 2-1: RMS on-state current versus case temperature (full cycle).

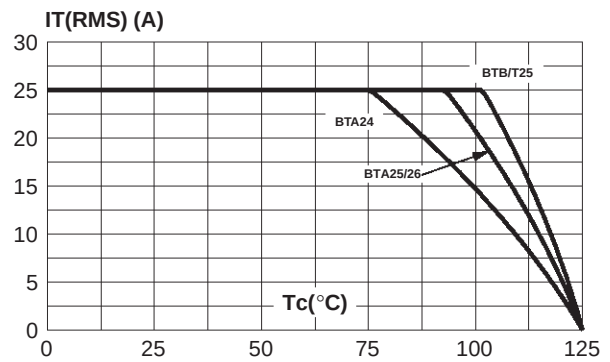


Fig. 2-2: D PAK RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: 35 μ m), full cycle.

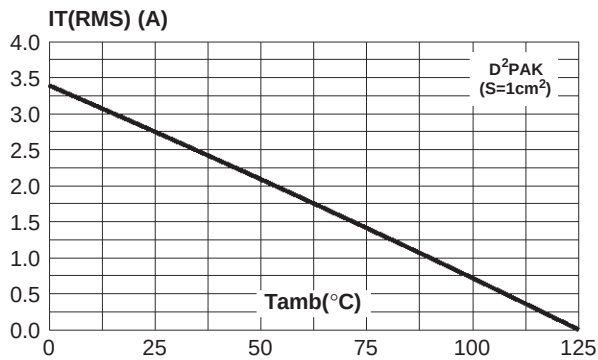


Fig. 3: Relative variation of thermal impedance versus pulse duration.

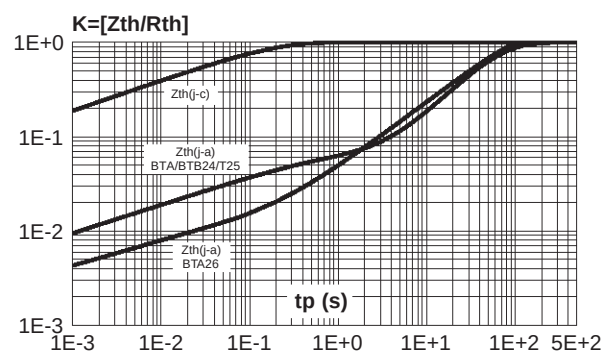


Fig. 4: On-state characteristics (maximum values).

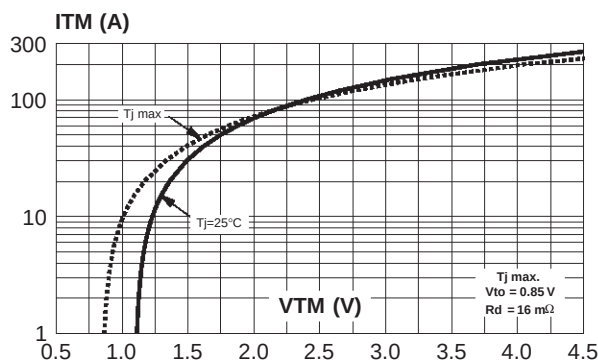


Fig. 5: Surge peak on-state current versus number of cycles.

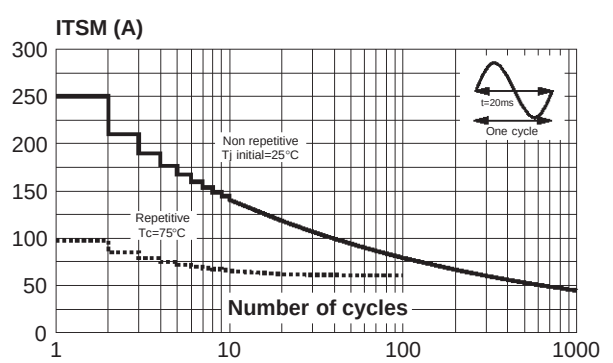


Fig. 6: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$, and corresponding value of I_t .

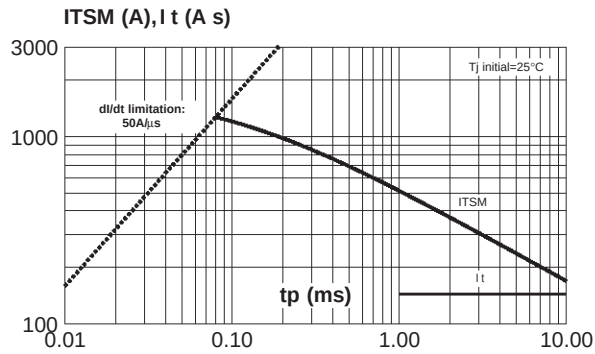


Fig. 8: Relative variation of critical rate of decrease of main current versus $(dV/dt)_c$ (typical values).

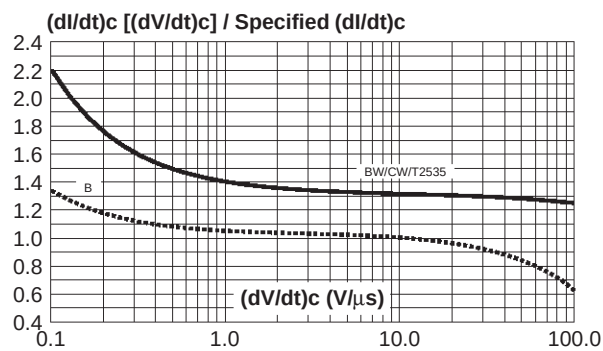


Fig. 10: D PAK Thermal resistance junction to ambient versus copper surface under tab (printed circuit board FR4, copper thickness: $35\text{ }\mu\text{m}$).

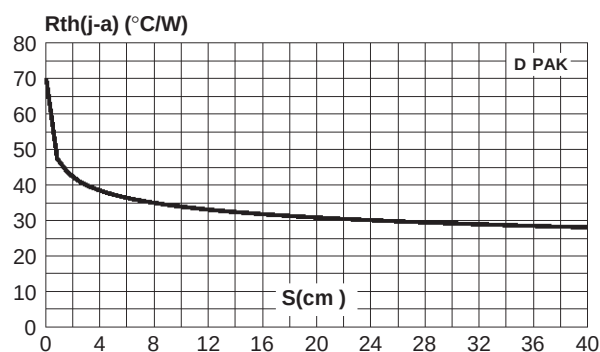


Fig. 7: Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values).

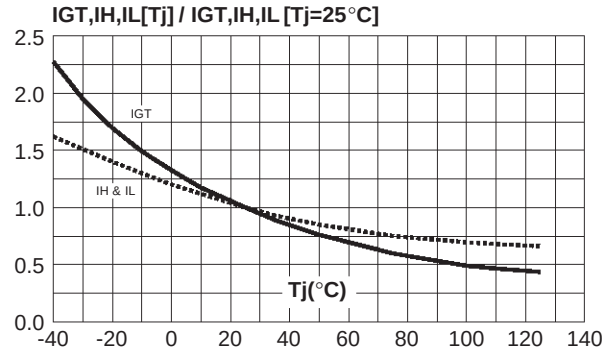
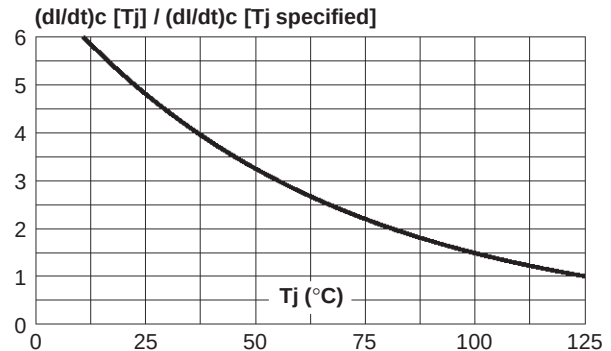
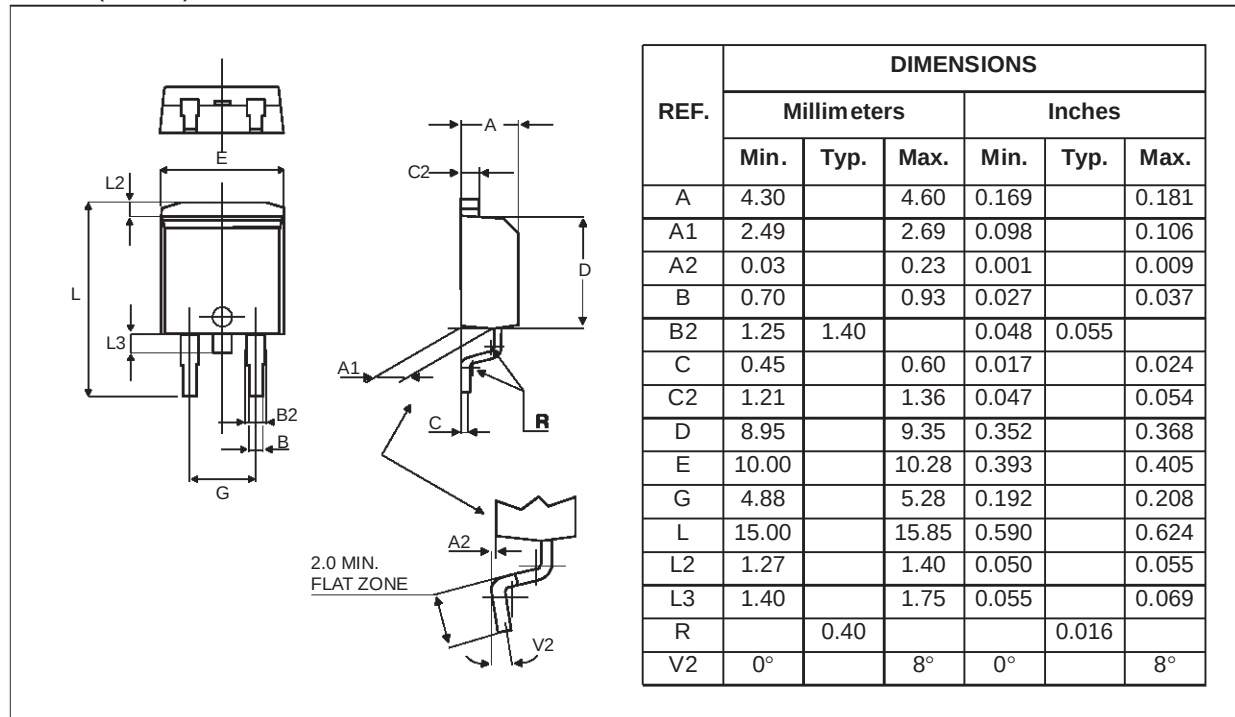


Fig. 9: Relative variation of critical rate of decrease of main current versus junction temperature.



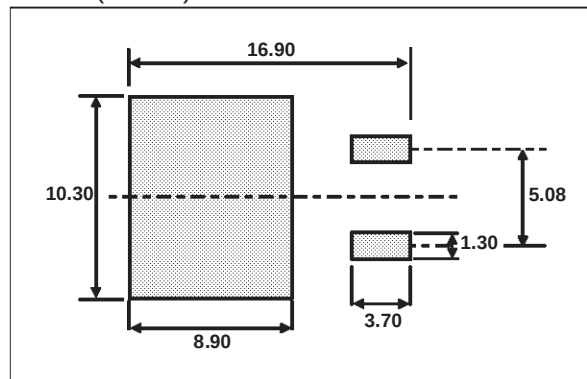
PACKAGE MECHANICAL DATA

D PAK (Plastic)



FOOTPRINT DIMENSIONS (in millimeters)

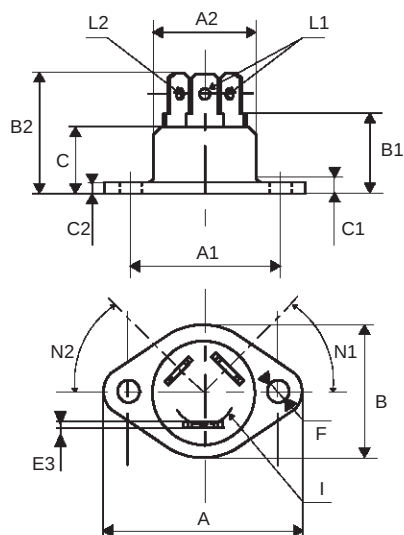
D PAK (Plastic)



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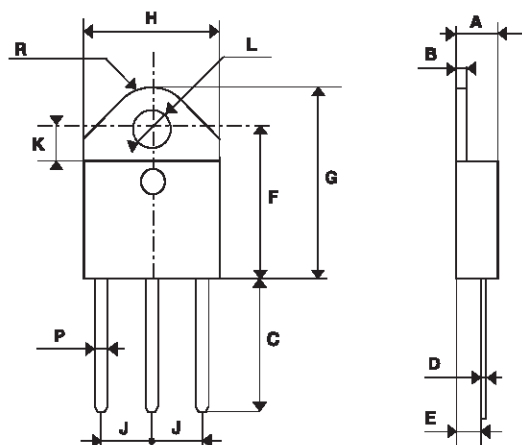
RD91 (Plastic)



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A		40.00		1.575
A1	29.90	30.30	1.177	1.193
A2		22.00		0.867
B		27.00		1.063
B1	13.50	16.50	0.531	0.650
B2		24.00		0.945
C		14.00		0.551
C1		3.50		0.138
C2	1.95	3.00	0.077	0.118
E3	0.70	0.90	0.027	0.035
F	4.00	4.50	0.157	0.177
I	11.20	13.60	0.441	0.535
L1	3.10	3.50	0.122	0.138
L2	1.70	1.90	0.067	0.075
N1	33°	43°	33°	43°
N2	28°	38°	28°	38°

PACKAGE MECHANICAL DATA

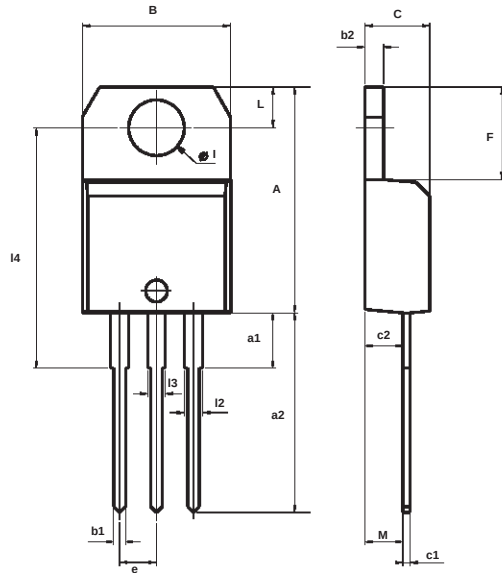
TOP3 (Plastic)



REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.4		4.6	0.173		0.181
B	1.45		1.55	0.057		0.061
C	14.35		15.60	0.565		0.614
D	0.5		0.7	0.020		0.028
E	2.7		2.9	0.106		0.114
F	15.8		16.5	0.622		0.650
G	20.4		21.1	0.815		0.831
H	15.1		15.5	0.594		0.610
J	5.4		5.65	0.213		0.222
K	3.4		3.65	0.134		0.144
L	4.08		4.17	0.161		0.164
P	1.20		1.40	0.047		0.055
R		4.60			0.181	

PACKAGE MECHANICAL DATA

TO-220AB (Plastic)



REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
I	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
I3	1.14		1.70	0.044		0.066
M		2.60			0.102	

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